1 Connection diagrams

Figure 1. Block diagram

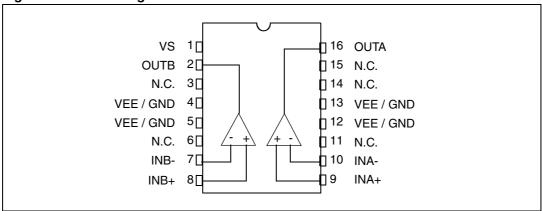
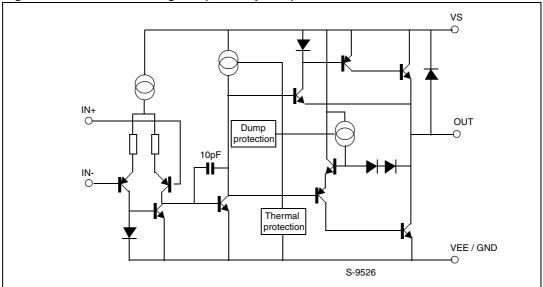


Figure 2. Schematic diagram (one amplifier)



L2720W Pin out

2 Pin out

Figure 3. Pin connection (top view)

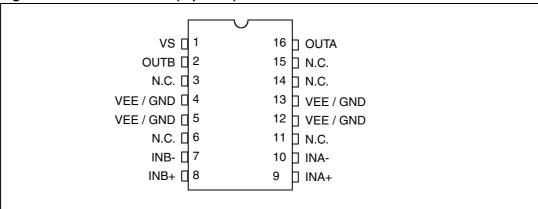


Table 2. Pin description

| Pin | Name | Туре | Description |
|-----|-----------|--------|---------------------------------|
| 1 | VS | Power | Power supply positive |
| 2 | OUTB | Output | Amplifier B output |
| 3 | N.C. | - | No internal connection |
| 4 | VEE / GND | Power | Power supply negative or ground |
| 5 | VEE / GND | Power | Power supply negative or ground |
| 6 | N.C. | - | No internal connection |
| 7 | INB- | Input | Amplifier B input |
| 8 | INB+ | Input | Amplifier B input |
| 9 | INA+ | Input | Amplifier A input |
| 10 | INA- | Input | Amplifier A input |
| 11 | N.C. | - | No internal connection |
| 12 | VEE / GND | Power | Power supply negative or ground |
| 13 | VEE / GND | Power | Power supply negative or ground |
| 14 | N.C. | - | No internal connection |
| 15 | N.C. | - | No internal connection |
| 16 | OUTA | Output | Amplifier A output |

3 Electrical specifications

3.1 Absolute maximum ratings

Table 3. Absolute maximum ratings

| Pin/symbol | Description | Min | Max | Unit |
|-----------------------------------|----------------------------------------|-----|-----------------|------|
| V _S | Supply voltage | - | 28 | V |
| V _{S-PK} | Peak supply voltage (50 ms) | - | 50 | ٧ |
| V _i | Input voltage range | - | V _s | ٧ |
| V _i | Differential input voltage range | - | ±V _S | ٧ |
| Io | DC output current | - | 1 | Α |
| I _{O-PK} | Peak output current (non repetitive) | - | 1.5 | Α |
| T _{op} | Operating ambient temperature range | -40 | 125 | °C |
| T _{stg} , T _j | Storage and junction temperature range | -40 | 150 | °C |

3.2 Thermal data

Table 4. Thermal data

| Device | Parameter | | Тур | Max | Unit |
|------------------------|----------------------------------------------|---|-----|-----|------|
| R _{th j-amb} | Thermal resistance junction to ambient (1) | - | 65 | - | °C/W |
| R _{th j-case} | Thermal resistance junction to case pins (2) | | 12 | - | °C/W |

^{1.} On double layer PCB with 4 cm² copper dissipating area

3.3 Recommended operating conditions

Table 5. Recommended operating conditions

| Symbol | Parameter | | Тур | Max | Unit |
|-----------------|------------------------------|------|-----|----------------------------------|------|
| V | Positive single power supply | 4.0 | - | 28 | V |
| V _S | Positive split power supply | 2.0 | - | 14 | V |
| M | Negative single power supply | - | 0 | - | V |
| V _E | Negative split power supply | -2.0 | - | -14 | V |
| V _{IN} | Input voltage | - | - | V _S to V _E | V |

^{2.} Referred to pins 4, 5, 12 and 13.

3.4 Electrical characteristics

The electrical specifications in *Table 6* below are given for operation under the conditions $V_S = 24$ V, $T_{amb} = -40$ °C to 125 °C and RI connected to GND, unless otherwise specified

Table 6. Electrical characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------------|----------------------------------------------------|------------------------------------------------------------------------------------------------|--------------------------|-----|-----|-----|------------|
| | Quicocont ourrent | V V /0 | T _{amb} = 25 °C | - | 10 | 15 | mA |
| Is | Quiescent current | $V_O = V_S / 2$ | - | - | 10 | 18 | |
| lib | Input bias current | 1,, | T _{amb} = 25 °C | - | 0.2 | 1 | μΑ |
| | | V _{CM} = 0 | - | - | 0.2 | 1 | |
| lob | Input offset current | ., . | T _{amb} = 25 °C | - | - | 100 | nA |
| IOD | | V _{CM} = 0 | - | - | - | 100 | |
| V | Input offset voltage | T _{amb} = 25 °C | | -10 | - | 10 | mV |
| V _{os} | input onset voltage | - | | -10 | - | 10 | Tilly |
| $\Delta V_{os}/\Delta T$ | Average temperature coefficient of V _{os} | - | | - | 20 | - | μV/° C |
| SR | Slew rate | Vin = -10 V to +10 V, $R_L = 2 k\Omega$, $C_L = 100 pF$, $Av = -1$, $T_{amb} = 25 °C$ | | - | 2 | - | V/μs |
| В | Gain-bandwidth product | - | | - | 1.2 | - | MHz |
| G _v | Open leep voltage gain | f = 100 Hz | | 70 | 80 | - | dB |
| | Open loop voltage gain | f = 1 kHz | | - | 60 | - | |
| CMRR | Common mode rejection ratio | f = 1 kHz | | 66 | 84 | - | dB |
| | Supply voltage rejection ratio | $f = 100 \text{ Hz}$ $R_G = 10 \text{ k}\Omega$ $V_R = 0.5 \text{ V}$ | V _s = 24 V | - | 70 | - | dB |
| SVRR | | | Vs = ±12 V | 60 | 75 | - | |
| | Drop voltage high | I _p = 100 mA | T _{amb} = 25 °C | - | 0.7 | 1 | |
| V | | | - | - | 0.8 | 1.5 | |
| $V_{DROP(H)}$ | | I _p = 1 A | T _{amb} = 25 °C | - | 1.0 | 1.5 | |
| | | | - | - | 1.1 | 1.5 | |
| V _{DROP(L)} | Drop voltage low | I _p = 100 mA | T _{amb} = 25 °C | - | 0.3 | 0.7 | |
| | | | - | - | 0.4 | 1 | V |
| | | I _p = 1 A | T _{amb} = 25 °C | - | 0.5 | 1 |] ' |
| | | | - | - | 1.3 | 1.5 | |
| Cs | Channel separation | $R_1 = 10 \Omega$: | V _s = 24 V | - | 60 | - | |
| | | | V _s = 6 V | - | 60 | - | dB |
| e _N | Input noise voltage | B = 22 Hz to 22 kHz, T _{amb} = 25 °C | | - | 10 | - | μV |



 Table 6.
 Electrical characteristics (continued)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|---------------------|-------------------------------------------------------------------------------|-----|-----|-----|------|
| I _N | Input noise current | B = 22 Hz to 22 kHz, T_{amb} = 25 °C | - | 200 | - | pА |
| φ _m | Phase margin | $R_L = 2 \text{ k}\Omega, C_L = 100 \text{ pF},$ $T_{amb} = 25 \text{ °C}$ | - | 65 | - | °C |
| A _m | Gain margin | $R_L = 2 \text{ k}\Omega, C_L = 100 \text{ pF},$ $T_{amb} = 25 \text{ °C}$ | - | 15 | - | dB |

3.5 Characterization curves

Figure 4. Quiescent current vs supply current

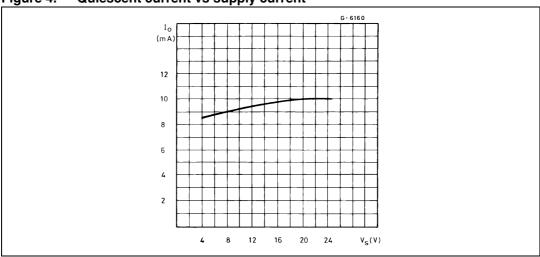
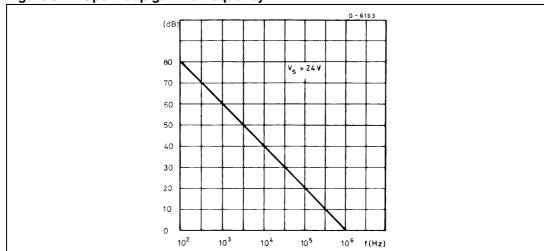


Figure 5. Open loop gain vs frequency



6/12 Doc ID 13407 Rev 2

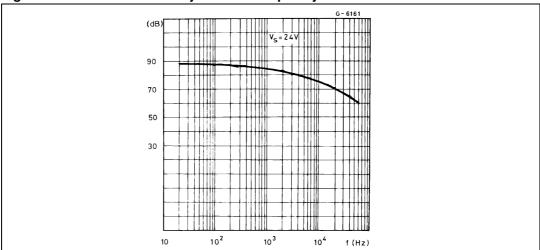
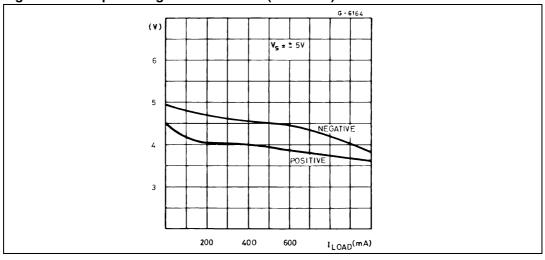
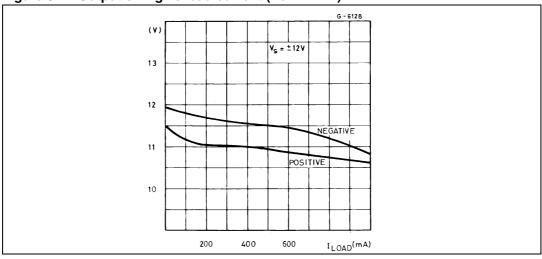


Figure 6. Common mode rejection vs frequency

Figure 7. Output swing vs load current ($Vs = \pm 5 V$)







5//

Doc ID 13407 Rev 2

Figure 9. Supply voltage rejection vs frequency

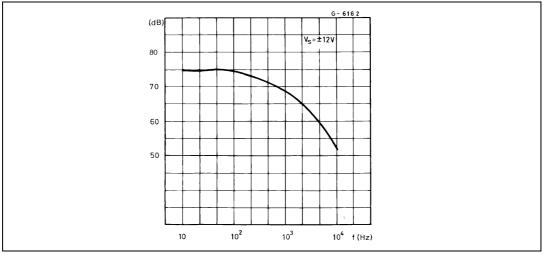


Figure 10. Channel separation vs frequency

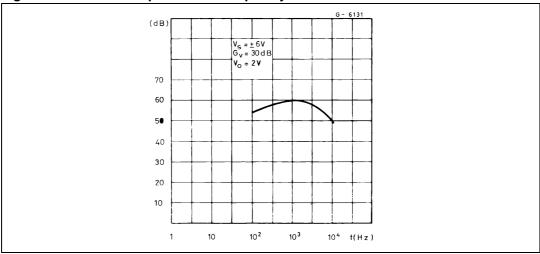
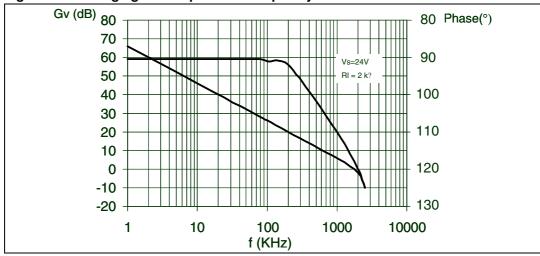


Figure 11. Voltage gain and phase vs frequency



8/12 Doc ID 13407 Rev 2

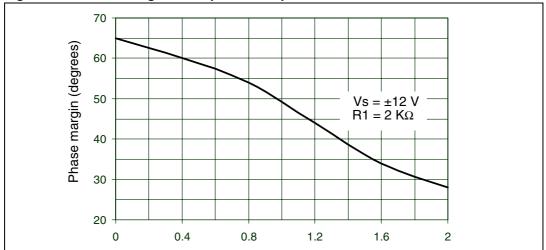


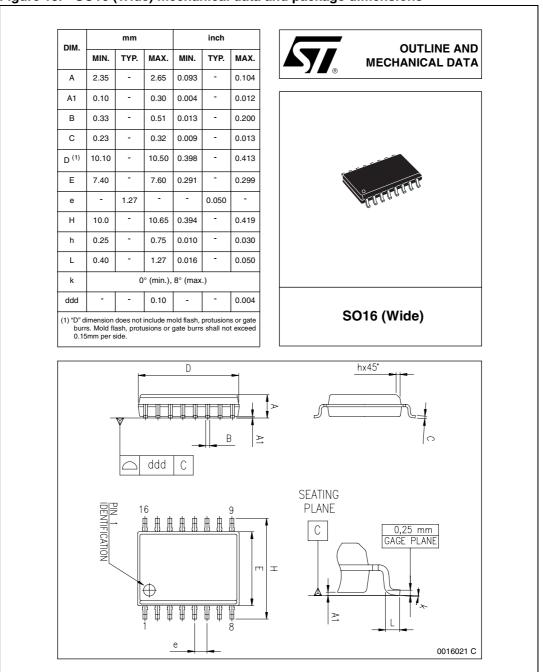
Figure 12. Phase margin vs output load capacitance

577

4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 13. SO16 (Wide) mechanical data and package dimensions



577

L2720W Revision history

5 Revision history

Table 7. Document revision history

| Date | Revision | Changes |
|-------------|----------|--------------------------------------------|
| 04-Apr-2007 | 1 | Initial release. |
| 03-Sep-2010 | 2 | Complete update and change in presentation |

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

12/12 Doc ID 13407 Rev 2

